

SN74LS251

8-Input Multiplexer with 3-State Outputs

The TTL/MSI SN74LS251 is a high speed 8-Input Digital Multiplexer. It provides, in one package, the ability to select one bit of data from up to eight sources. The LS251 can be used as a universal function generator to generate any logic function of four variables. Both assertion and negation outputs are provided.

- Schottky Process for High Speed
- Multifunction Capability
- On-Chip Select Logic Decoding
- Inverting and Non-Inverting 3-State Outputs
- Input Clamp Diodes Limit High Speed Termination Effects

GUARANTEED OPERATING RANGES

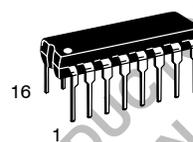
Symbol	Parameter	Min	Typ	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current - High			-2.6	mA
I _{OL}	Output Current - Low			24	mA



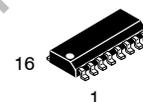
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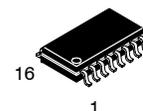
LOW
POWER
SCHOTTKY



PLASTIC
N SUFFIX
CASE 648



SOIC
D SUFFIX
CASE 751B



SOEIAJ
M SUFFIX
CASE 966

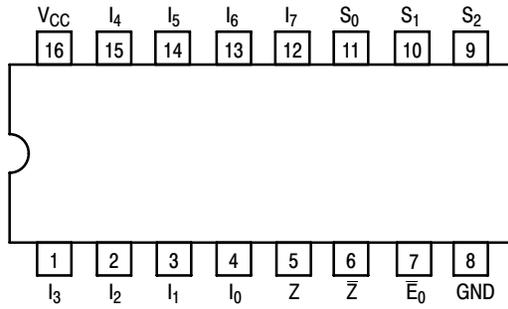
ORDERING INFORMATION

Device	Package	Shipping
SN74LS251N	16 Pin DIP	2000 Units/Box
SN74LS251D	SOIC-16	38 Units/Rail
SN74LS251DR2	SOIC-16	2500/Tape & Reel
SN74LS251M	SOEIAJ-16	See Note 1
SN74LS251MEL	SOEIAJ-16	See Note 1

1. For ordering information on the EIAJ version of the SOIC package, please contact your local ON Semiconductor representative.

SN74LS251

CONNECTION DIAGRAM DIP (TOP VIEW)



PIN NAMES

$S_0 - S_2$	Select Inputs
E_0	Output Enable (Active LOW) Inputs
$I_0 - I_7$	Multiplexer Inputs
Z	Multiplexer Output
\bar{Z}	Complementary Multiplexer Output

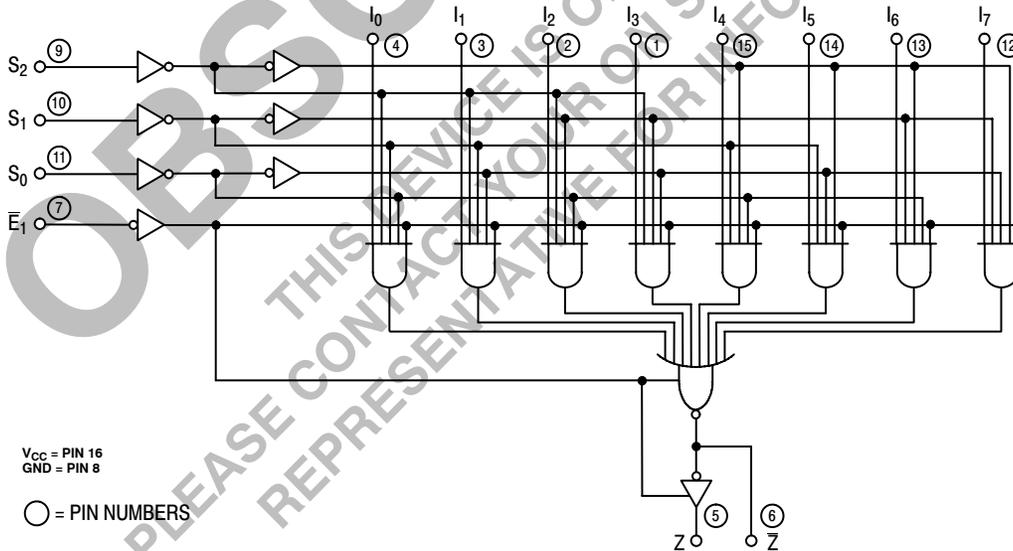
LOADING (Note a)

	HIGH	LOW
$S_0 - S_2$	0.5 U.L.	0.25 U.L.
E_0	0.5 U.L.	0.25 U.L.
$I_0 - I_7$	0.5 U.L.	0.25 U.L.
Z	65 U.L.	15 U.L.
\bar{Z}	65 U.L.	15 U.L.

NOTES:

a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

LOGIC DIAGRAM



FUNCTIONAL DESCRIPTION

The LS251 is a logical implementation of a single pole, 8-position switch with the switch position controlled by the state of three Select inputs, S₀, S₁, S₂. Both assertion and negation outputs are provided. The Output Enable input (\bar{E}_0) is active LOW. When it is activated, the logic function provided at the output is:

$$Z = \bar{E}_0 \cdot [I_0 \cdot \bar{S}_0 \cdot \bar{S}_1 \cdot \bar{S}_2 + I_1 \cdot \bar{S}_0 \cdot \bar{S}_1 \cdot S_2 + I_2 \cdot \bar{S}_0 \cdot S_1 \cdot \bar{S}_2 + I_3 \cdot \bar{S}_0 \cdot S_1 \cdot S_2 + I_4 \cdot S_0 \cdot \bar{S}_1 \cdot \bar{S}_2 + I_5 \cdot S_0 \cdot \bar{S}_1 \cdot S_2 + I_6 \cdot S_0 \cdot S_1 \cdot \bar{S}_2 + I_7 \cdot S_0 \cdot S_1 \cdot S_2]$$

When the Output Enable is HIGH, both outputs are in the high impedance (high Z) state. This feature allows multiplexer expansion by tying the outputs of up to 128 devices together. When the outputs of the 3-state devices are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. The Output Enable signals should be designed to ensure there is no overlap in the active LOW portion of the enable voltage.

TRUTH TABLE

\bar{E}_0	S ₂	S ₁	S ₀	I ₀	I ₁	I ₂	I ₃	I ₄	I ₅	I ₆	I ₇	Z	Z
H	X	X	X	X	X	X	X	X	X	X	X	(Z)	(Z)
L	L	L	L	L	X	X	X	X	X	X	X	H	L
L	L	L	L	H	X	X	X	X	X	X	X	L	H
L	L	L	H	X	L	X	X	X	X	X	X	H	L
L	L	L	H	X	H	X	X	X	X	X	X	L	H
L	L	H	L	X	X	L	X	X	X	X	X	H	L
L	L	H	L	X	X	H	X	X	X	X	X	L	H
L	L	H	H	X	X	X	L	X	X	X	X	H	L
L	L	H	H	X	X	X	H	X	X	X	X	L	H
L	H	L	L	X	X	X	X	L	X	X	X	H	L
L	H	L	L	X	X	X	X	H	X	X	X	L	H
L	H	L	H	X	X	X	X	X	L	X	X	H	L
L	H	L	H	X	X	X	X	X	H	X	X	L	H
L	H	H	L	X	X	X	X	X	X	L	X	H	L
L	H	H	L	X	X	X	X	X	H	X	X	L	H
L	H	H	H	X	X	X	X	X	X	X	L	H	L
L	H	H	H	X	X	X	X	X	X	X	H	L	H

H = HIGH Voltage Level
 L = LOW Voltage Level
 X = Don't Care
 (Z) = High impedance (Off)

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DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

Symbol	Parameter	Limits			Unit	Test Conditions
		Min	Typ	Max		
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} = -18 mA
V _{OH}	Output HIGH Voltage	2.4	3.1		V	V _{CC} = MIN, I _{OH} = MAX, V _{IN} = V _{IH} or V _{IL} per Truth Table
V _{OL}	Output LOW Voltage		0.25	0.4	V	V _{CC} = V _{CC} MIN, V _{IN} = V _{IL} or V _{IH} per Truth Table
			0.35	0.5	V	
I _{OZH}	Output Off Current HIGH			20	μA	V _{CC} = MAX, V _{OUT} = 2.7 V
I _{OZL}	Output Off Current LOW			-20	μA	V _{CC} = MAX, V _{OUT} = 0.4 V
I _{IH}	Input HIGH Current			20	μA	V _{CC} = MAX, V _{IN} = 2.7 V
				0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V
I _{OS}	Short Circuit Current (Note 2)	-30		-130	mA	V _{CC} = MAX
I _{CC}	Power Supply Current			10	mA	V _{CC} = MAX, V _E = 0 V
				12	mA	V _{CC} = MAX, V _E = 4.5 V

2. Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25°C, V_{CC} = 5.0 V)

Symbol	Parameter	Limits			Unit	Test Conditions
		Min	Typ	Max		
t _{PLH} t _{PHL}	Propagation Delay, Select to Z Output		20	33	ns	C _L = 15 pF, R _L = 2.0 kΩ
			21	33		
t _{PLH} t _{PHL}	Propagation Delay, Select to Z Output		29	45	ns	
			28	45		
t _{PLH} t _{PHL}	Propagation Delay, Data to Z Output		10	15	ns	
			9.0	15		
t _{PLH} t _{PHL}	Propagation Delay, Data to Z Output		17	28	ns	
			18	28		
t _{PZH} t _{PZL}	Output Enable Time to Z Output		17	27	ns	
			24	40		
t _{PZH} t _{PZL}	Output Enable Time to Z Output		30	45	ns	
			26	40		
t _{PHZ} t _{PLZ}	Output Disable Time to Z Output		37	55	ns	C _L = 5.0 pF, R _L = 667 kΩ
			15	25		
t _{PHZ} t _{PLZ}	Output Disable Time to Z Output		30	45	ns	
			15	25		

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3-STATE AC WAVEFORMS

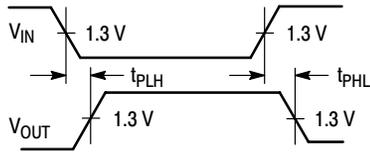


Figure 1.

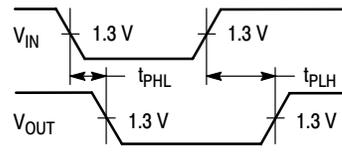


Figure 2.

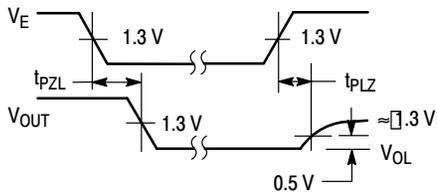


Figure 3.

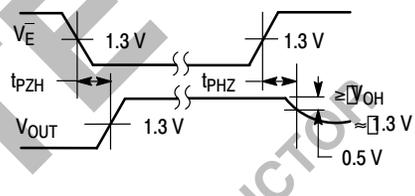
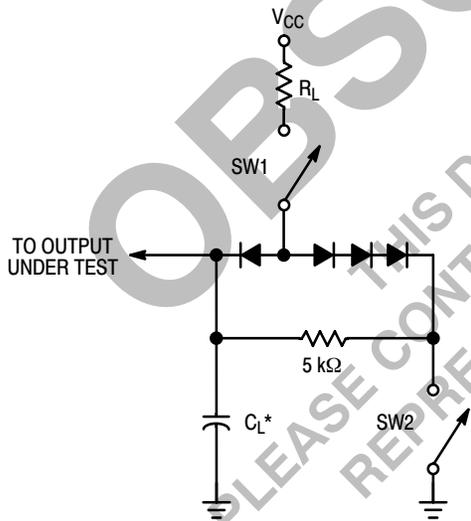


Figure 4.

AC LOAD CIRCUIT



* Includes Jig and Probe Capacitance.

SWITCH POSITIONS

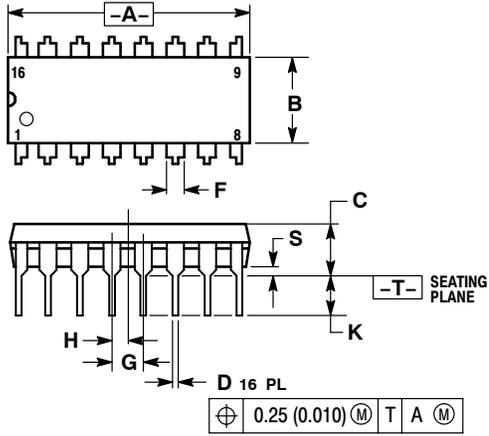
SYMBOL	SW1	SW2
t_{PZH}	Open	Closed
t_{PZL}	Closed	Open
t_{PLZ}	Closed	Closed
t_{PHZ}	Closed	Closed

Figure 5.

SN74LS251

PACKAGE DIMENSIONS

N SUFFIX
PLASTIC PACKAGE
CASE 648-08
ISSUE R



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.740	0.770	18.80	19.55
B	0.250	0.270	6.35	6.85
C	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100 BSC		2.54 BSC	
H	0.050 BSC		1.27 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
M	0°		10°	
S	0.020	0.040	0.51	1.01

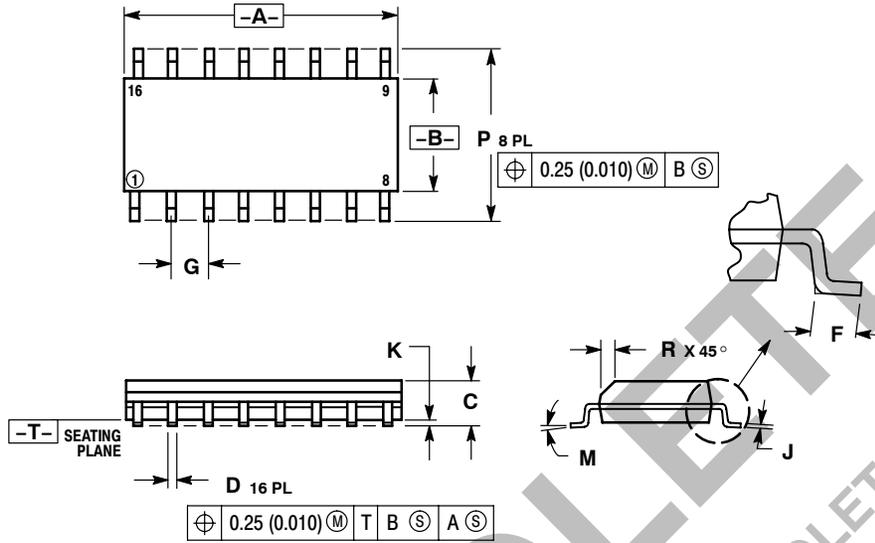
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SN74LS251

PACKAGE DIMENSIONS

D SUFFIX
 PLASTIC SOIC PACKAGE
 CASE 751B-05
 ISSUE J



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.80	10.00	0.386	0.393
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°		7°	
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

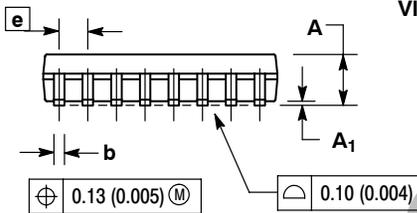
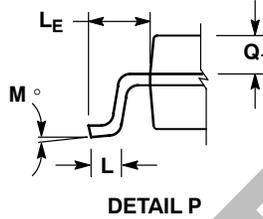
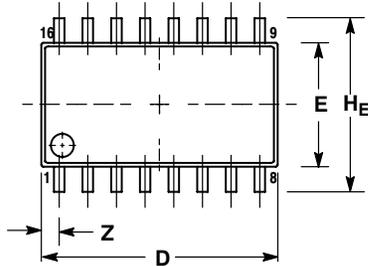
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PACKAGE DIMENSIONS

M SUFFIX
SOEIAJ PACKAGE
CASE 966-01
ISSUE O



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	---	2.05	---	0.081
A ₁	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
c	0.18	0.27	0.007	0.011
D	9.90	10.50	0.390	0.413
E	5.10	5.45	0.201	0.215
e	1.27 BSC		0.050 BSC	
HE	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
LE	1.10	1.50	0.043	0.059
M	0° 10°		0° 10°	
Q ₁	0.70	0.90	0.028	0.035
Z	---	0.78	---	0.031

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